

SKM 50GB063D

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SEMITRANS® 2

Superfast NPT-IGBT Modules

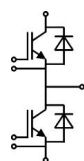
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Features

- NPT = non punch-through IGBT technology
- High short circuit capability, self limiting to $6 \times I_C$
- Pos. temp.-coeff. of V_{CEsat}
- Isolated copper baseplate

Typical Applications

- Switched mode power supplies
- UPS
- Three phase inverters for servo / AC motor speed control



GB

Absolute Maximum Ratings		$T_c = 25^\circ\text{C}$, unless otherwise specified		
Symbol	Conditions	Values		Units
IGBT				
V_{CES}	$T_j = 25^\circ\text{C}$	600		V
I_C	$T_j = 150^\circ\text{C}$	$T_{case} = 25^\circ\text{C}$	70	A
		$T_{case} = 75^\circ\text{C}$	50	A
I_{CRM}	$I_{CRM} = 2 \times I_{Cnom}$	100		A
V_{GES}		± 20		V
t_{psc}	$V_{CC} = 300\text{ V}; V_{GE} \leq 20\text{ V}; T_j = 125^\circ\text{C}$ $V_{CES} < 600\text{ V}$	10		μs
Inverse Diode				
I_F	$T_j = 150^\circ\text{C}$	$T_{case} = 25^\circ\text{C}$	75	A
		$T_{case} = 80^\circ\text{C}$	50	A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$	100		A
I_{FSM}	$t_p = 10\text{ ms; sin.}$ $T_j = 150^\circ\text{C}$	440		A
Module				
$I_{t(RMS)}$		200		A
T_{vj}		- 40 ... + 150		$^\circ\text{C}$
T_{stg}		- 40 ... + 125		$^\circ\text{C}$
V_{isol}	AC, 1 min.	2500		V

Characteristics			T _c = 25 °C, unless otherwise specified			
Symbol	Conditions		min.	typ.	max.	Units
IGBT						
V _{GE(th)}	V _{GE} = V _{CE} , I _C = 1 mA		4,5	5,5	6,5	V
I _{CES}	V _{GE} = 0 V, V _{CE} = V _{CES}	T _j = 25 °C		0,1	0,3	mA
V _{CE0}	T _j = 25 °C			1,05		V
	T _j = 125 °C			1		V
r _{CE}	V _{GE} = 15 V	T _j = 25°C		25		mΩ
		T _j = 125°C		33		mΩ
V _{CE(sat)}	I _{Cnom} = 50 A, V _{GE} = 15 V	T _j = 25°C _{chiplev.}		2,1	2,5	V
		T _j = 125°C _{chiplev.}		2,4	2,8	V
C _{ies}	V _{CE} = 25, V _{GE} = 0 V	f = 1 MHz		2,8		nF
C _{oes}				0,3		nF
C _{res}				0,2		nF
Q _G	V _{GE} = 0V...+15V			120		nC
R _{Gint}	T _j = °C			0		Ω
t _{d(on)}	R _{Gon} = 22 Ω	V _{CC} = 300V I _{Cnom} = 50A T _j = 125 °C V _{GE} = ± 15V		50		ns
t _r				40		ns
E _{on}			2,5		mJ	
t _{d(off)}	R _{Goff} = 22 Ω			300		ns
t _f				30		ns
E _{off}				1,8		mJ
R _{th(j-c)}	per IGBT				0,5	K/W

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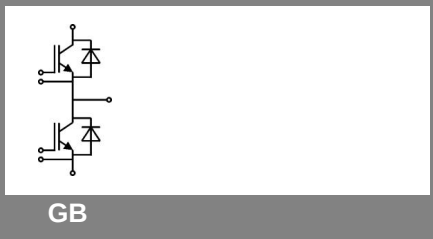
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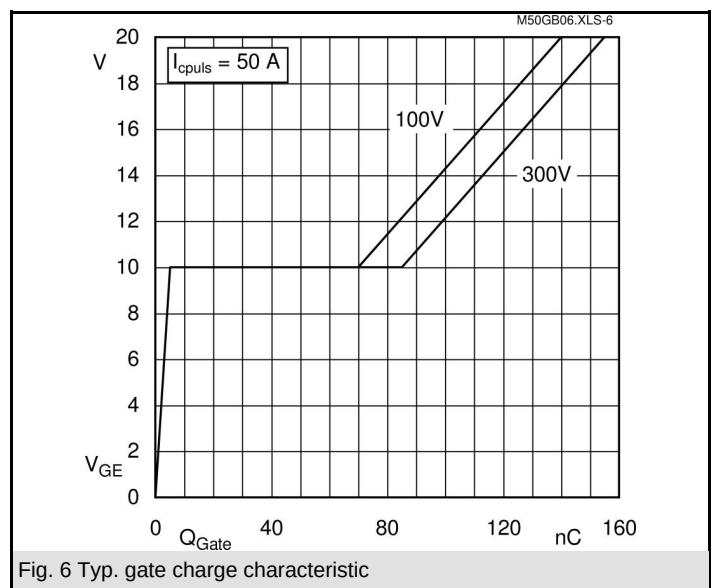
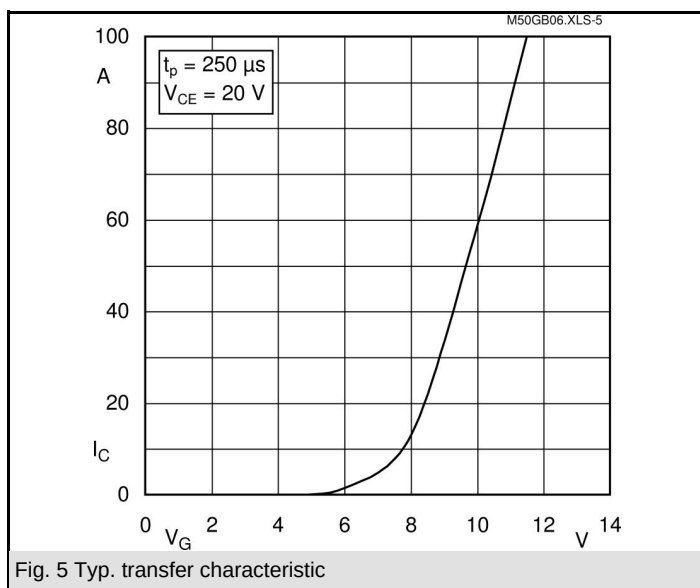
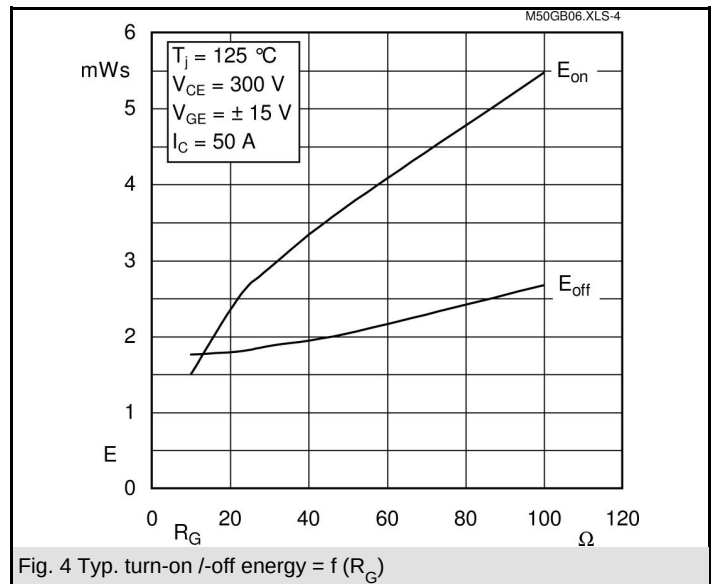
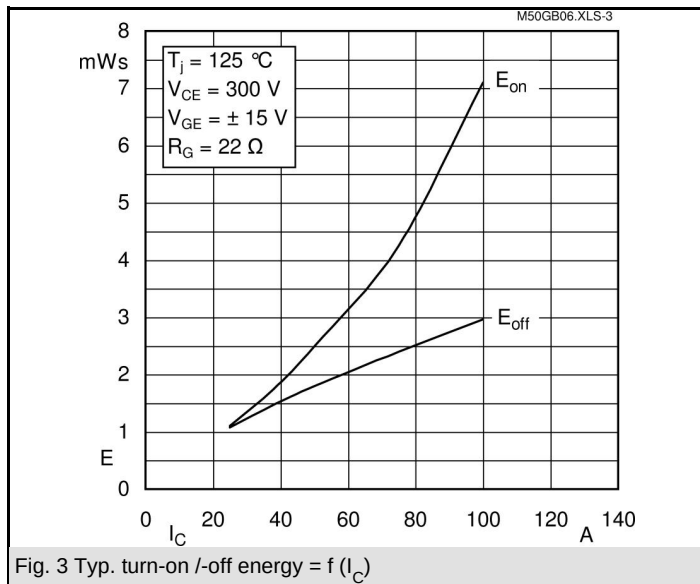
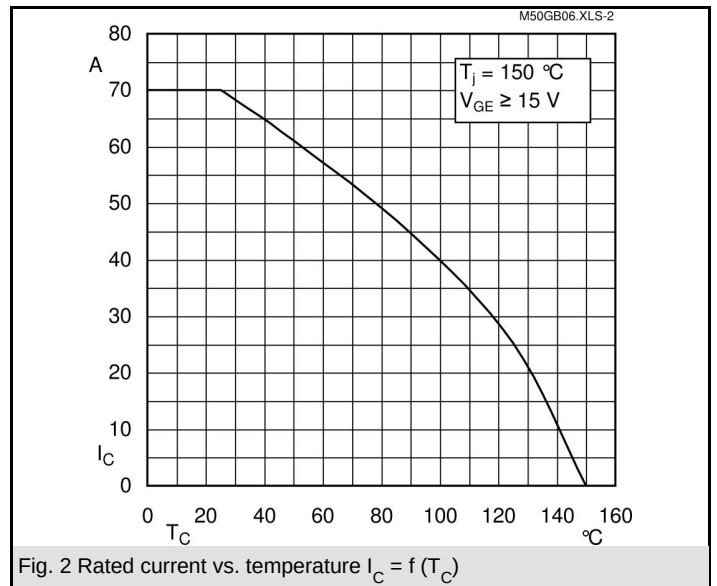
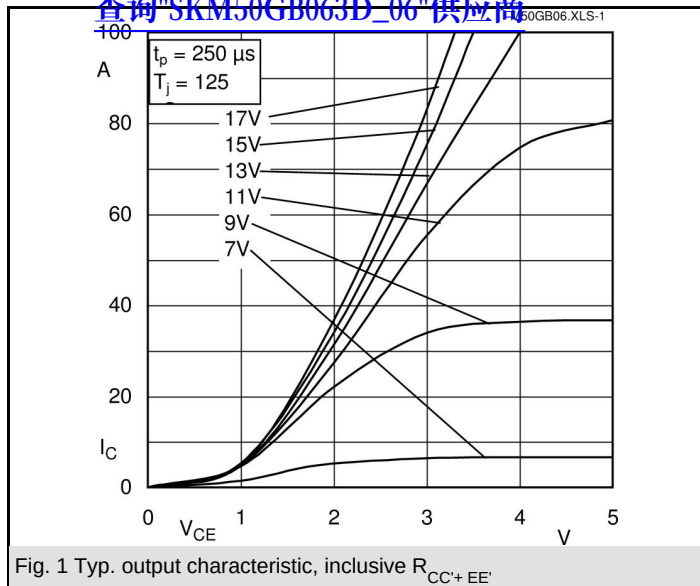
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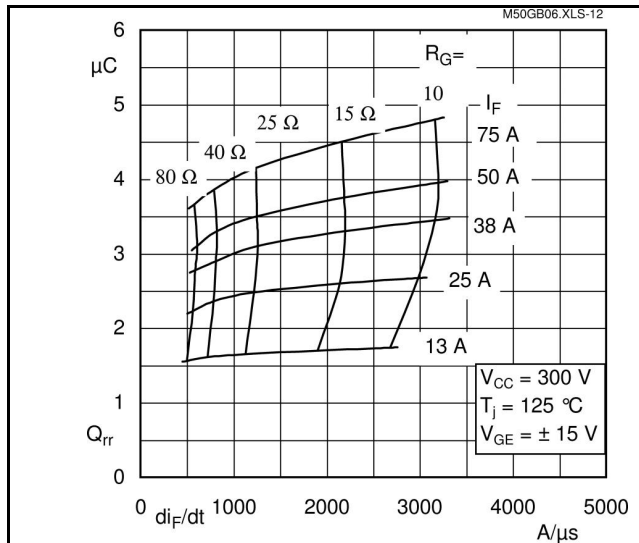
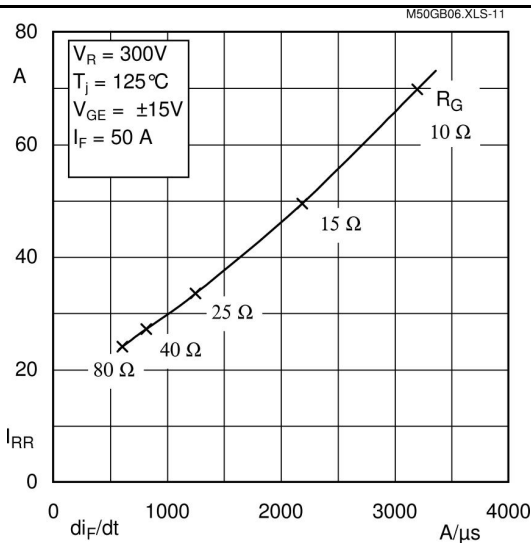
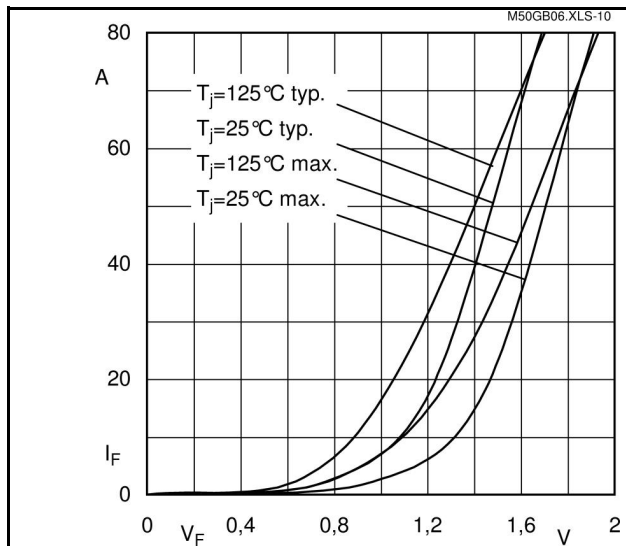
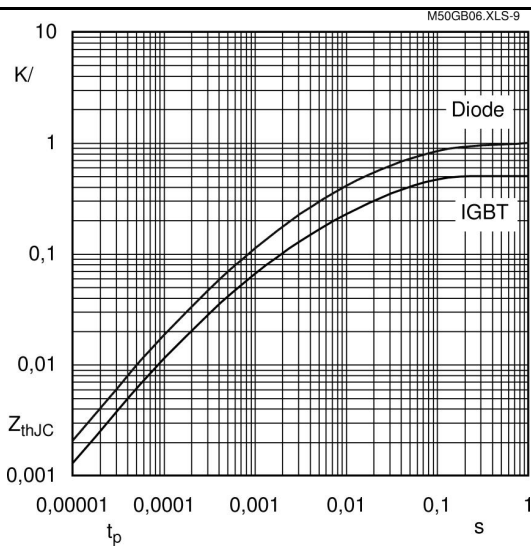
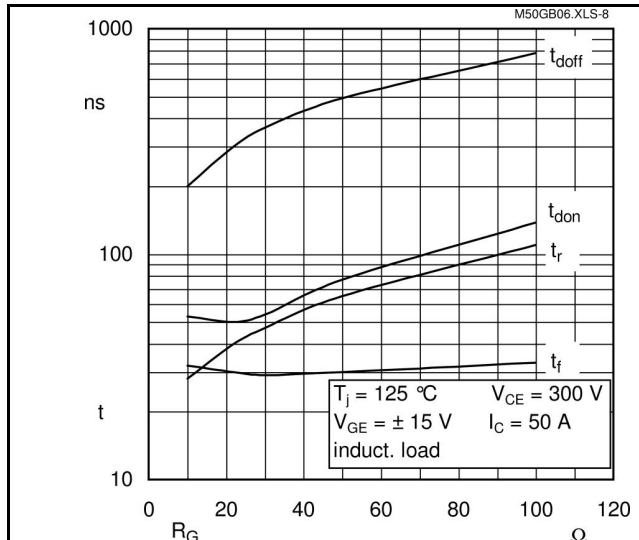
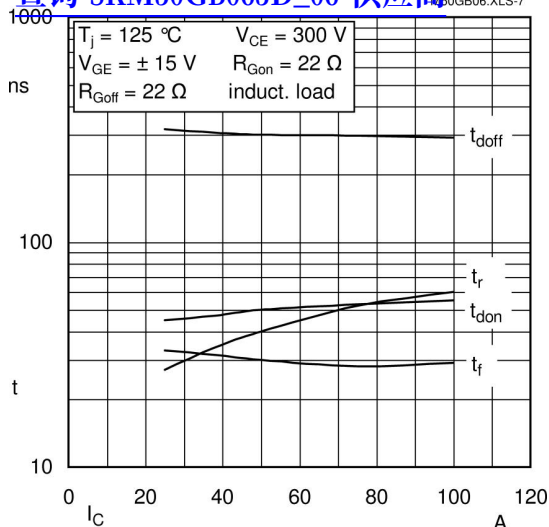
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Symbol	Conditions	Values	Units
Z_{th}			
Z_{th(j-c)l}			
R _i	i = 1	290	mk/W
R _i	i = 2	145	mk/W
R _i	i = 3	54	mk/W
R _i	i = 4	11	mk/W
tau _i	i = 1	0,0382	s
tau _i	i = 2	0,0078	s
tau _i	i = 3	0,0017	s
tau _i	i = 4	0,0001	s
Z_{th(j-c)D}			
R _i	i = 1	550	mk/W
R _i	i = 2	340	mk/W
R _i	i = 3	92	mk/W
R _i	i = 4	18	mk/W
tau _i	i = 1	0,0761	s
tau _i	i = 2	0,045	s
tau _i	i = 3	0,011	s
tau _i	i = 4	0,0002	s
Z_{th(r-s)}			
R _i	i = 1		mk/W
R _i	i = 2		mk/W
R _i	i = 3		mk/W
R _i	i = 4		mk/W
tau _i	i = 1		s
tau _i	i = 2		s
tau _i	i = 3		s
tau _i	i = 4		s

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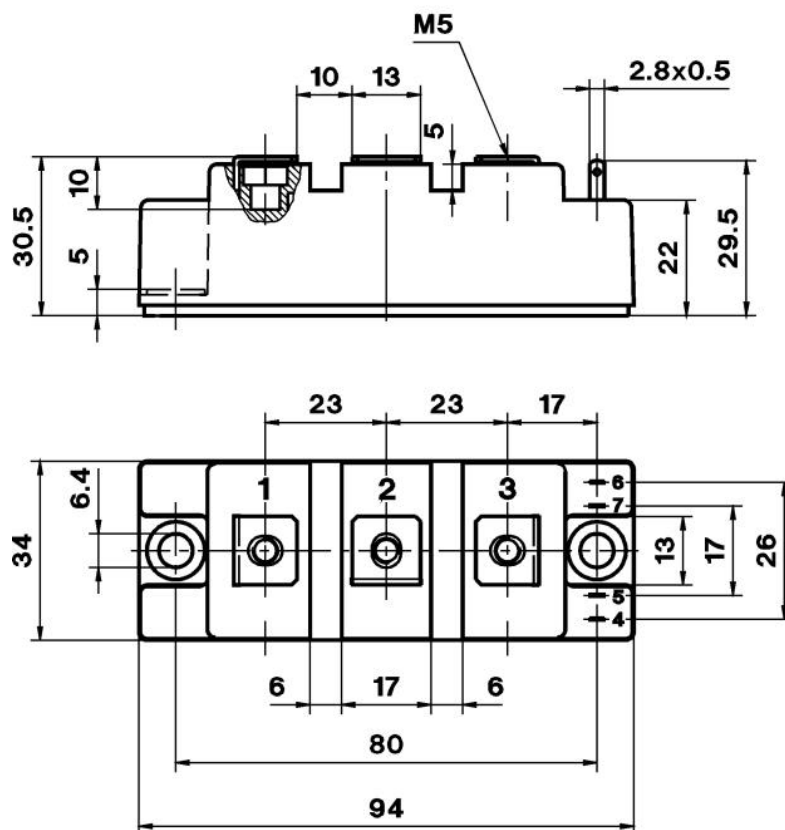


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CASED61

File no. E 63 532



Case D 61

